Diode Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.453 inches

## Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-203

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case and quality assurance level tx

#### **Overall Width Across Flats:**

0.688 inches

Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

50.0 reverse voltage, instantaneous and 50.0 working peak reverse voltage

## **Current Rating Per Characteristic:**

70.00 amperes forward current, average absolute

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

# **Specification Data:**

81349-mil-s-19500/550 government specification

# Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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